

PSMN8R5-40MLD

N-channel 40 V, 8.5 mΩ, logic level MOSFET in LFPAK33 using NextPower-S3 technology 10 February 2020

Product data sheet

1. General description

60 A, logic level N-channel enhancement mode MOSFET in 175 °C LFPAK33 package using advanced TrenchMOS Superjunction technology. This product has been designed and qualified for high efficiency applications at high switching frequencies.

2. Features and benefits

- Avalanche rated, 100% tested
- NextPower-S3 technology delivers 'superfast switching with soft body-diode recovery'
- Low Q_{RR}, Q_G and Q_{GD} for high system efficiency, especially at high switching frequencies
- · Low spiking and ringing for low EMI designs
- High reliability clip bonded and solder die attach Mini Power SO8 package; no glue, no wire • bonds, qualified to 175 °C
- Exposed leads can be wave soldered, visual solder joint inspection and high quality solder joints
- Low parasitic inductance and resistance

3. Applications

- Secondary side synchronous rectification
- DC-to-DC converters •
- Brushless DC motor drive
- LED lighting

4. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	40	V
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	60	А
Tj	junction temperature			-55	-	175	°C
Static chara	acteristics				_		
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 15 A; T _j = 25 °C; Fig. 10		-	7.2	8.5	mΩ
		V _{GS} = 4.5 V; I _D = 15 A; T _j = 25 °C; <u>Fig. 10</u>		-	9	11	mΩ
Dynamic ch	naracteristics						
Q _{GD}	gate-drain charge	I _D = 15 A; V _{DS} = 20 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13		0.6	2.1	4.2	nC

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Q _{G(tot)}	total gate charge	I _D = 15 A; V _{DS} = 20 V; V _{GS} = 10 V; Fig. 12; Fig. 13	12	19	27	nC

[1] 60A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source		D
2	S	source		
3	S	source		G (H
4	G	gate		mbb076 S
mb	D	Mounting base; connected to drain	LFPAK33 (SOT1210)	

6. Marking

Table 3. Marking codes	
Type number	Marking code
PSMN8R5-40MLD	8D5L40

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	40	V
V _{DSM}	peak drain-source voltage	$t_p \le 20 \text{ ns}; f \le 500 \text{ kHz}; E_{DS(AL)} \le 200 \text{ nJ};$ pulsed		-	45	V
V _{DGR}	drain-gate voltage	25 °C ≤ $T_j \le 175$ °C; $R_{GS} = 20 \text{ k}\Omega$		-	40	V
V _{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	59	W
ID	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	60	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	42	А
I _{DM}	peak drain current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$; Fig. 3		-	239	А
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drai	n diode					
Is	source current	T _{mb} = 25 °C		-	59	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \ \mu s$; $T_{mb} = 25 \ ^{\circ}C$		-	239	Α

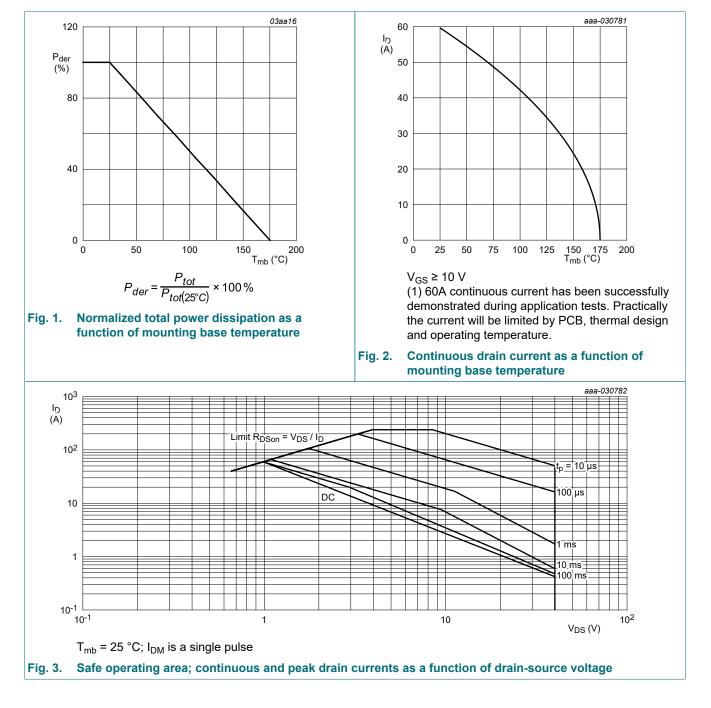
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Symbol	Parameter	Conditions		Min	Max	Unit
Avalanche ruge	gedness			·		
E _{DS(AL)S}	source avalanche energy	$ \begin{split} &I_{D} = 25 \text{ A}; V_{sup} \leq \ 40 \text{ V}; R_{GS} = 50 \ \Omega; \\ &V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \ ^{\circ}\text{C}; unclamped; \\ &t_{p} = 80 \ \mu\text{s} \end{split} $	[2]	-	46	mJ
		$ \begin{split} &I_{D} = 15 \text{ A}; V_{sup} \leq \ 40 \text{ V}; R_{GS} = 50 \ \Omega; \\ &V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \ ^{\circ}\text{C}; unclamped; \\ &t_{p} = 180 \ \mu\text{s} \end{split} $	[2]	-	70	mJ

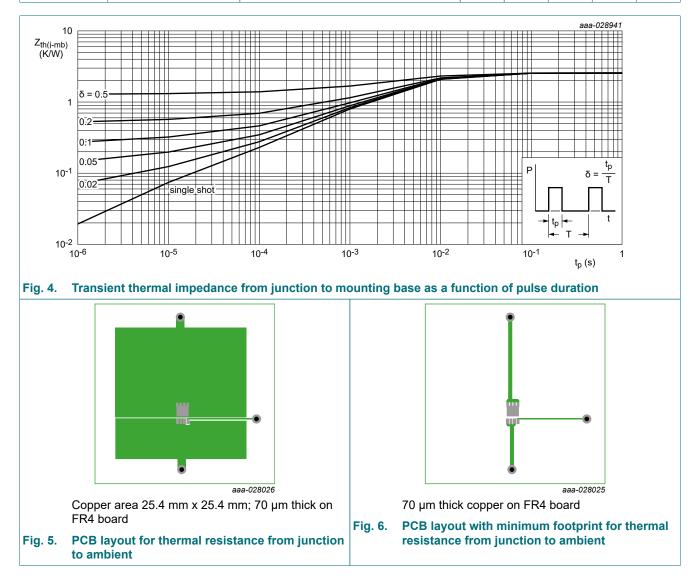
[1] 60A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

[2] Protected by 100% test



8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 4	-	2.33	2.56	K/W
R _{th(j-a)}	thermal resistance from	Fig. 5	-	50	-	K/W
junction to ambient	Fig. 6	-	130	-	K/W	



9. Characteristics

Table 6. Characteristics								
Symbol	Parameter	Conditions		Min	Тур	Мах	Unit	
Static characteristics								
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C		40	-	-	V	
	breakdown voltage	I_D = 250 µA; V_{GS} = 0 V; T_j = -55 °C		36	-	-	V	

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{GS(th)}	gate-source threshold voltage	$I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1.45	1.77	2.15	V
$\Delta V_{GS(th)} / \Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-4.2	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 32 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{DS} = 32 V; V _{GS} = 0 V; T _j = 125 °C	-	0.3	-	μA
I _{GSS}	gate leakage current	V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
		V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C	-	2	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 15 A; T _j = 25 °C; <u>Fig. 10</u>	-	7.2	8.5	mΩ
		V _{GS} = 10 V; I _D = 15 A; T _j = 175 °C; <u>Fig. 11</u>	-	-	16.5	mΩ
		V _{GS} = 4.5 V; I _D = 15 A; T _j = 25 °C; <u>Fig. 10</u>	-	9	11	mΩ
		V _{GS} = 4.5 V; I _D = 15 A; T _j = 175 °C; <u>Fig. 11</u>	-	-	21.4	mΩ
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	0.3	0.8	2	Ω
Dynamic cha	racteristics					
Q _{G(tot)}	total gate charge	I_D = 15 A; V_{DS} = 20 V; V_{GS} = 10 V; Fig. 12; Fig. 13	12	19	27	nC
		I _D = 15 A; V _{DS} = 20 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13	6	9	13	nC
		$I_D = 0 \text{ A}; V_{DS} = 0 \text{ V}; V_{GS} = 10 \text{ V}$	-	10	-	nC
Q _{GS}	gate-source charge	I_D = 15 A; V_{DS} = 20 V; V_{GS} = 4.5 V;	2.1	3.6	5.4	nC
Q _{GS(th)}	pre-threshold gate- source charge	Fig. 12; Fig. 13	1.2	2.1	3.2	nC
$Q_{GS(th-pl)}$	post-threshold gate- source charge		0.9	1.5	2.3	nC
Q _{GD}	gate-drain charge		0.6	2.1	4.2	nC
V _{GS(pl)}	gate-source plateau voltage	I _D = 15 A; V _{DS} = 20 V; <u>Fig. 12</u> ; <u>Fig. 13</u>	-	2.8	-	V
C _{iss}	input capacitance	V _{DS} = 20 V; V _{GS} = 0 V; f = 1 MHz;	842	1296	1814	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 14</u>	249	383	536	pF
C _{rss}	reverse transfer capacitance	_	15	49	108	pF
t _{d(on)}	turn-on delay time	V_{DS} = 20 V; R _L = 1.2 Ω; V _{GS} = 4.5 V;	-	9.5	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$	-	9.4	-	ns
t _{d(off)}	turn-off delay time		-	11	-	ns
t _f	fall time		-	5.6	-	ns
Q _{oss}	output charge		-	11.4	-	nC
Source-drain	diode	·			1	
V _{SD}	source-drain voltage	I _S = 15 A; V _{GS} = 0 V; T _i = 25 °C; <u>Fig. 15</u>	-	0.85	1	V

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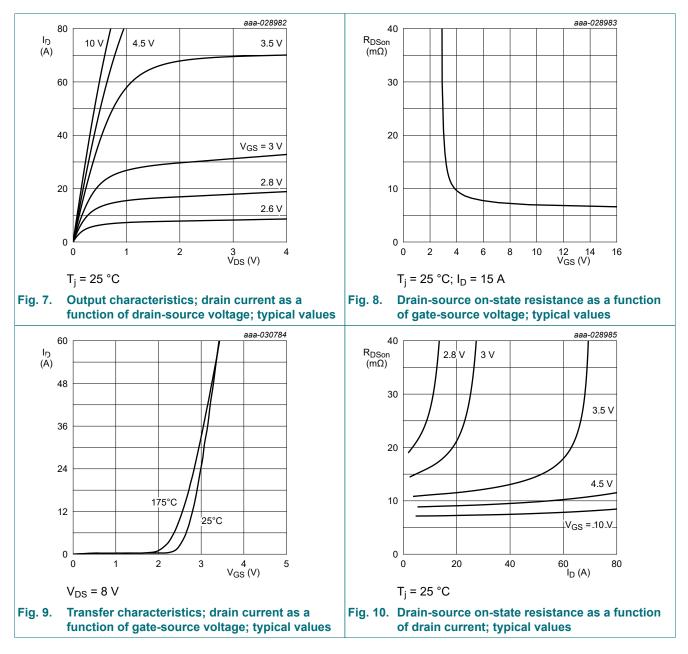
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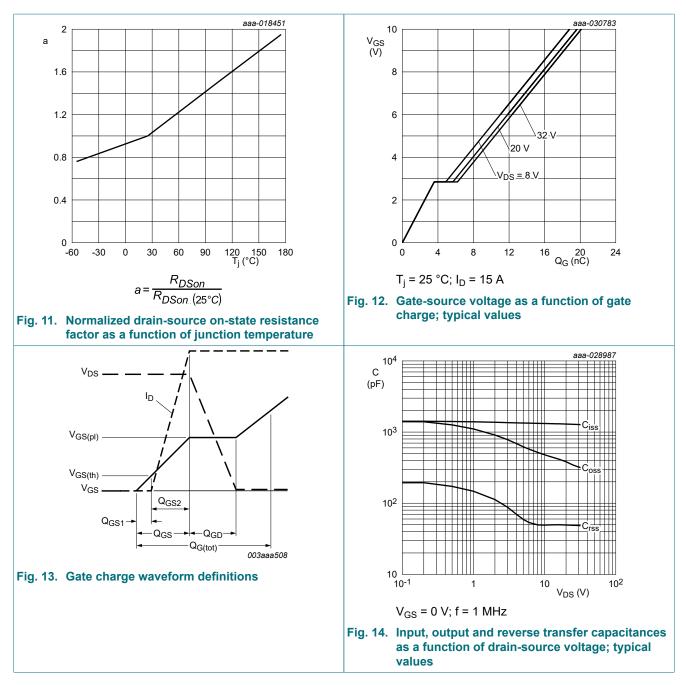
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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
t _{rr}	reverse recovery time	I_{S} = 15 A; dI _S /dt = -100 A/µs; V _{GS} = 0 V;		-	22	-	ns
Qr	recovered charge	V _{DS} = 20 V; <u>Fig. 16</u> [1]	[1]	-	15	-	nC
t _a	reverse recovery rise time			-	13	-	ns
t _b	reverse recovery fall time			-	8.2	-	ns

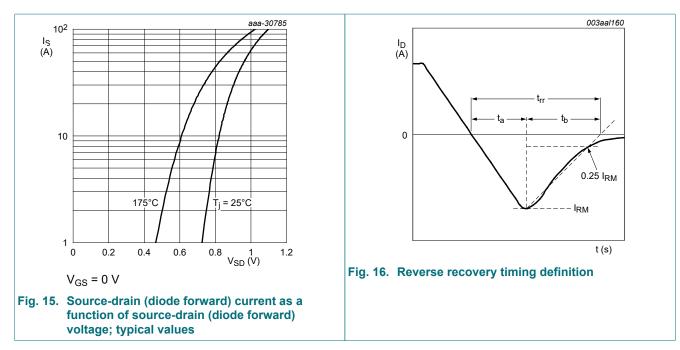
[1] includes capacitive recovery



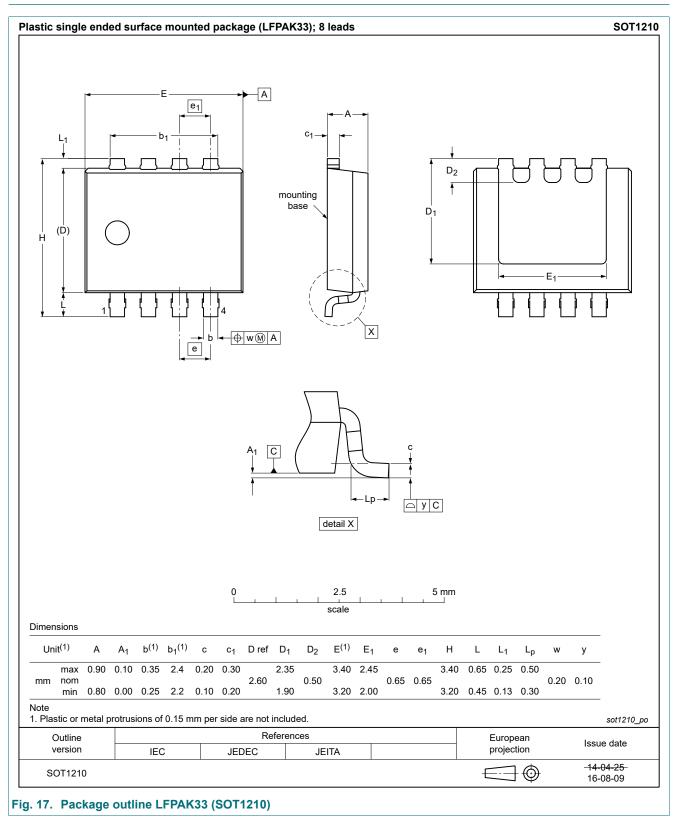


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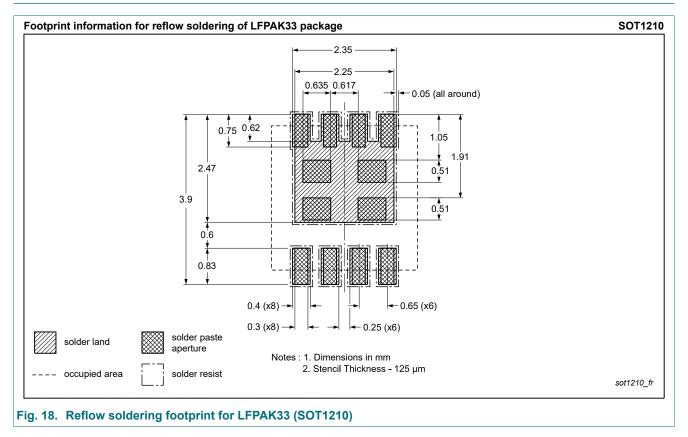
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10. Package outline



11. Soldering



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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